

DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 1, 4-6, 11-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No: 5,874,012 to Kanai et al in view of US Patent 6,056,823 to Sajoto et al.

Regarding Claim 1, and 13, Referring to (*Fig.-1, 5, 6*) Kanai et al teach that a plasma processing apparatus, comprising: gas supply (15, 16) means for supplying a gas including a reactant gas to an interior of a chamber (4); pressure control (17, 18, 19, 20) means for controlling an internal pressure of the chamber (Col. 5, Line 2-8); plasma generation means for generating a plasma of the gas in the interior of the chamber (4); and a susceptor (10), installed

in a lower portion of the interior of the chamber, for supporting a substrate (11) to be processed, and further comprising a wall surface protecting member (6) formed in a cylindrical form and provided in the interior of the chamber, for preventing adhesion of a plasma processing-associated product onto an inner wall surface of the chamber (Col. 4, Line 35-67, Col. 5, Line 1-29) and the chamber includes a chamber step portion (see Fig. 5) provided to the inner wall surface of the chamber, for supporting the wall surface protecting member (6) from below to cover the inner wall surface of the chamber located above the susceptor (10). Further Kanai et al teach that there is a gap (14) between the outer cylinder (5) and inner cylinder (6) and in the gap, a corrugated plate (30) contacts the lower outer cylinder and the inner cylinder with a spring force and the contact force between the outer cylinder and the inner cylinder is increased by springs 31, 33 and the corrugated plate 30 for the purpose of absorbing any difference of thermal expansion between the outer cylinder and the inner cylinder (Col. 7, Line 16-37) (Fig. 5, 6).

Regarding Claim 4, Referring to (Fig.-1) Kanai et al teach that the wall surface protecting member is made of a ceramic (Col. 4, Line 49-51).

Regarding Claim 5, 6, Referring to (Fig.-1) Kanai et al teach that the wall surface protecting member is made of a metal and the metal is aluminum (Col. 6, Line 57-65).

Regarding Claim 11, Referring to (Fig.-1) Kanai et al teach that heating means for heating a wall surface of the chamber (Col. 5, Line 13-20).

Regarding Claim 12, Referring to (Fig.-1) Kanai et al teach that the heating means heats the wall surface of the chamber to 100°C or higher (Col 5, Line 15-20, Col 6, Line 1-6).

But Kanai et al does not teach that the wall surface protecting member has a plurality of projections along an axial direction of the wall.

However, Sajoto et al teach that the apparatus of the invention substantially as claimed and also teach that the wall surface protecting member (28) has a plurality of projections (23) along the axial direction of the wall and connects with a point contact, the inner wall surface of the chamber and the chamber step portion, and wherein the wall surface protecting member is supported in the chamber by the point contact for the purpose of preventing heat transfer between the wall and the protecting member. (Figure 2)

Thus, it would have been obvious to one of ordinary skill in the art at the time applicant's claimed invention was made to have provided the wall surface protecting member having a plurality of projections along the axial direction of the wall, provided on an outer wall surface and in a lower end portion of the wall surface protecting member, for contacting, by point contact, the inner wall surface of the chamber and the chamber step portion, and wherein the wall surface protecting member is supported in the chamber by the point contact in Kanai et al in order to prevent thermal conduction from the wall surface projecting member to the wall protection member as and improve the reproducibility of plasma treatment by keeping the wall protection member at a constant temperature as taught by Sajoto et al.

Claims 7-8 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No: U.S. Patent No: 5,874,012 to Kanai et al in view of US Patent 6,056,823 to Sajoto et al as applied to claims 1, 4-6, and 11-13 above, and further in view of JP2002222767A to Shibazaki.

Regarding Claims 7, 8, Referring to (Fig.-2) Kanai et al and Sajoto et al teach that the apparatus of the invention substantially as claimed.

But Kanai et al and Sajoto et al fail to teach that the wall surface protecting member has a surface oxidized and roughened.

However, Shibazaki teach that the wall surface protecting member has a surface oxidized and roughened for the purpose of suppressing the generation of particles within a vacuum chamber and does not deteriorate the degree of vacuum in the vacuum device (Abstract, Drawings 1-3).

Thus, it would have been obvious to one of ordinary skill in the art at the time applicant's claimed invention was made to have provided wall surface protecting member with oxidized and roughened surface in Kanai et al and Sajoto et al in order to suppress the generation of particles within a vacuum chamber and does not deteriorate the degree of vacuum in the vacuum device as taught by Shibazaki.

Claim 9 is rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No: 5,874,012 to Kanai et al in view of US Patent 6,056,823 to Sajoto et al as applied to claims 1, 4-6, 11-12 above, and further in view of 07-283143 A to Kazuo et al.

Regarding Claim 9, Referring to (Fig.-2) Kanai et al and Sajoto et al teach that the apparatus of the invention substantially as claimed.

But Kanai et al and Sajoto et al fail to teach that the gas supply means is installed while passing through a hole provided in the wall surface protecting member.

However, Kazuo et al teach that the gas supply (8, 9) means is installed while passing through a hole/opening provided in the wall surface protecting member (7b, 71a, 71b) (See

Drawing-3) for the purpose of producing plasma in the plasma production room (1) and the hole/opening is for inserting the reactant gas installation tube and come to the center section of the plasma production room (Page 4, Paragraph 0017, Page 7, Paragraph 0038).

Thus, it would have been obvious to one of ordinary skill in the art at the time applicant's claimed invention was made to have provided the gas supply means is installed while passing through a hole provided in the wall surface protecting member in Kanai et al and Sajoto et al in order to produce plasma in the plasma production room and the hole/opening is for inserting the reactant gas installation tube and come to the center section of the plasma production room as taught by Kazuo et al.

Response to Arguments

Applicant's arguments with respect to claims 1, 4-9, and 11-13 have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jeffrie R. Lund whose telephone number is (571) 272-1437. The examiner can normally be reached on Monday-Thursday (10:00 am - 9:00 pm).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Parviz Hassanzadeh can be reached on (571) 272-1435. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/Jeffrie R. Lund/
Primary Examiner
Art Unit 1792

JRL
7/21/08